Diode Semiconductor Device - Page 1 of 1



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# Inclosure Material:

Glass

# **Overall Length:**

Between 0.150 inches and 0.300 inches

## **Terminal Length:**

1.000 inches

## **Overall Diameter:**

Between 0.080 inches and 0.150 inches

#### Mounting Method:

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

1000.0 working peak reverse voltage, peak total value

### Current Rating Per Characteristic:

333.00 milliamperes forward current, total rms megahertz

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

## Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0